



SBOS141C - JANUARY 1984 - REVISED SEPTEMBER 2009

PRECISION VOLTAGE-TO-CURRENT CONVERTER/TRANSMITTER

FEATURES

- 4mA TO 20mA TRANSMITTER
- SELECTABLE INPUT/OUTPUT RANGES: 0V to +5V, 0V to +10V Inputs 0mA to 20mA, 5mA to 25mA Outputs Other Ranges
- 0.005% MAX NONLINEARITY, 14 BIT
- PRECISION +10V REFERENCE OUTPUT
- SINGLE-SUPPLY OPERATION
- WIDE SUPPLY RANGE: 13.5V to 40V

DESCRIPTION

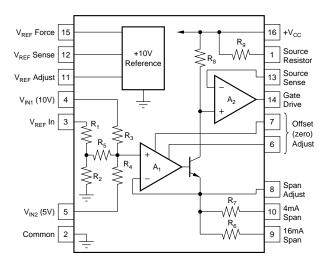
The XTR110 is a precision voltage-to-current converter designed for analog signal transmission. It accepts inputs of 0 to 5V or 0 to 10V and can be connected for outputs of 4mA to 20mA, 0mA to 20mA, 5mA to 25mA, and many other commonly used ranges.

A precision on-chip metal film resistor network provides input scaling and current offsetting. An internal 10V voltage reference can be used to drive external circuitry.

The XTR110 is available in 16-pin plastic DIP, ceramic DIP and SOL-16 surface-mount packages. Commercial and industrial temperature range models are available.

APPLICATIONS

- INDUSTRIAL PROCESS CONTROL
- PRESSURE/TEMPERATURE TRANSMITTERS
- CURRENT-MODE BRIDGE EXCITATION
- GROUNDED TRANSDUCER CIRCUITS
- CURRENT SOURCE REFERENCE FOR DATA ACQUISITION
- PROGRAMMABLE CURRENT SOURCE FOR TEST EQUIPMENT
- POWER PLANT/ENERGY SYSTEM MONITORING





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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ABSOLUTE MAXIMUM RATINGS(1)

Power Supply, +V _{CC} 40V
Input Voltage, V _{IN1} , V _{IN2} , V _{REF IN} +V _{CC}
See text regarding safe negative input voltage range.
Storage Temperature Range: A, B55°C to +125°C
K, U40°C to +85°C
Output Short-Circuit Duration, Gate Drive
and V _{REF} Force Continuous to common and +V _{CC}
Output Current Using Internal 50Ω Resistor 40mA

NOTE: (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability.

ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

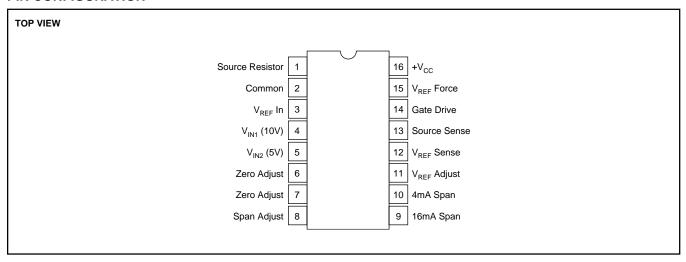
ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION(1)

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	TEMPERATURE RANGE
XTR110AG	DIP-16 Ceramic	JD	−40°C to +85°C
XTR110BG	DIP-16 Ceramic	JD	-40°C to +85°C
XTR110KP	DIP-16 Plastic	N	0°C to +70°C
XTR110KU	SOL-16 Surface-Mount	DW	0°C to +70°C

NOTE: (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

PIN CONFIGURATION





ELECTRICAL CHARACTERISTICS

At T_A = +25°C and V_CC = +24V and R_L = 250 $\Omega^{\star\star}$, unless otherwise specified.

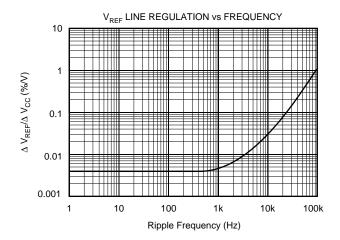
		ХТ	R110AG, KP,	KU		XTR110BG			
PARAMETER	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS	
TRANSMITTER									
Transfer Function			I ₀ = 10 [(V _{REE} In/16) + ('	$V_{IN1}/4) + (V_{IN2}/2)$)] /R _{span}			
Input Range: V _{IN1} (5)	Specified Performance	0)	*	SI AIV	*	l v	
V _{IN2}	Specified Performance	0		+5	*		*	l v	
Current, I _O	Specified Performance ⁽¹⁾	4		20	*		*	mA	
, 0	Derated Performance ⁽¹⁾	0		40	*		*	mA	
Nonlinearity	16mA/20mA Span ⁽²⁾		0.01	0.025		0.002	0.005	% of Span	
Offset Current, I _{OS}	$I_{O} = 4mA^{(1)}$							70 01 01	
Initial	(1)		0.2	0.4		0.02	0.1	% of Span	
vs Temperature	(1)		0.0003	0.005		*	0.003	% of Span/°C	
vs Supply, V _{CC}	(1)		0.0005	0.005		*	*	% of Span/V	
Span Error	I _O = 20mA		0.0000	0.000				70 or opany	
Initial	(1)		0.3	0.6		0.05	0.2	% of Span	
vs Temperature	(1)		0.0025	0.005		0.0009	0.003	% of Span/°C	
vs Temperature vs Supply, V _{CC}	(1)		0.0023	0.005		v.0009	v.003	% of Span/V	
Output Resistance	From Drain of FET (Q _{EXT}) ⁽³⁾		10 x 10 ⁹	0.005		*		Ω	
Input Resistance			27					kΩ	
input Resistance	V _{IN1}		27			*		kΩ	
	V _{IN2}							1	
Domestic Deservation	V _{REF} In		19					kΩ	
Dynamic Response	T 0.40/ / 0		4-						
Settling Time	To 0.1% of Span		15					μs	
01 . D .	To 0.01% of Span		20					μs	
Slew Rate			1.3			^		mA/μs	
VOLTAGE REFERENCE									
Output Voltage		+9.95	+10	+10.05	+9.98	*	+10.02	V	
vs Temperature			35	50		15	30	ppm/°C	
vs Supply, V _{CC}	Line Regulation		0.0002	0.005		*	*	%/V	
vs Output Current	Load Regulation		0.0005	0.01		*	*	%/mA	
vs Time			100			*		ppm/1k hrs	
Trim Range		-0.100		+0.25	*		*	V	
Output Current	Specified Performance	10			*			mA	
POWER SUPPLY									
Input Voltage, V _{CC}		+13.5		+40	*		*	l v	
Quiescent Current	Excluding I _O		3	4.5		*	*	mA	
TEMPERATURE RANGE									
Specification: AG, BG		-40		+85	*		*	°C	
KP, KU		-4 0		+70				l ∘c	
,				I -	*		*	°C °C	
Operating: AG, BG		-55 25		+125				°C	
KP, KU		-25		+85				"	

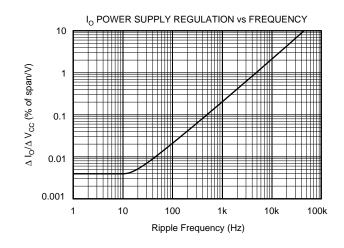
 $^{^{\}star}$ Specifications same as AG/KP grades. ** Specifications apply to the range of R_L shown in Typical Performance Curves.

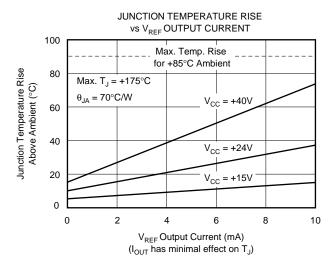
NOTES: (1) Including internal reference. (2) Span is the change in output current resulting from a full-scale change in input voltage. (3) Within compliance range limited by $(+V_{CC}-2V)+V_{DS}$ required for linear operation of the FET. (4) For V_{REF} adjustment circuit see Figure 3. (5) For extended I_{REF} drive circuit see Figure 4. (5) Unit may be damaged. See *Input Voltage Range* section.

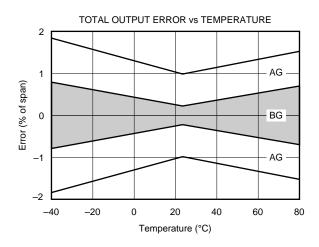
TYPICAL PERFORMANCE CURVES

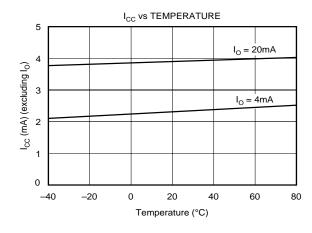
 $T_A = +25$ °C, $V_{CC} = 24$ VDC, $R_L = 250\Omega$, unless otherwise noted.

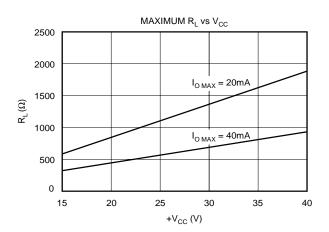






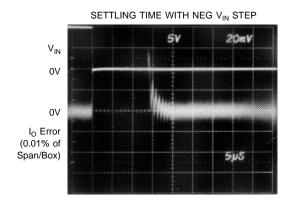


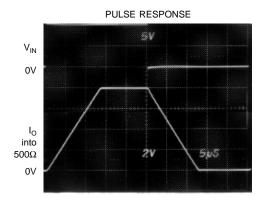


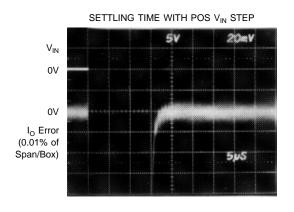


TYPICAL PERFORMANCE CURVES (Continued)

At T_A = +25°C, V_{CC} = 24VDC, R_L = 250 Ω , unless otherwise noted.









APPLICATIONS INFORMATION

Figure 1 shows the basic connections required for 0V to 10V input and 4ma to 20mA output. Other input voltage and output current ranges require changes in connections of pins 3, 4, 5, 9 and 10 as shown in the table of Figure 1.

The complete transfer function of the XTR110 is:

$$I_{O} = \frac{10\left[\frac{(V_{REF\,IN})}{16} + \frac{(V_{IN1})}{4} + \frac{(V_{IN2})}{2}\right]}{R_{SPAN}}$$
(1)

 R_{SPAN} is the total impedance seen at the emitter of the internal NPN transistor. This impedance varies depending on how pins 8, 9 and 10 are configured. Typical operating region configurations are shown in Figure 1. An external R_{SPAN} can be connected for different output current ranges as described later.

EXTERNAL TRANSISTOR

An external pass transistor, Q_{EXT} , is required as shown in Figure 1. This transistor conducts the output signal current. A P-channel MOSFET transistor is recommended. It must

have a voltage rating equal or greater than the maximum power supply voltage. Various recommended types are shown in Table I.

MANUFACTURER	PART NO.	BV _{DSS} ⁽¹⁾	BV _{GS} ⁽¹⁾	PACKAGE
Ferranti	ZVP1304A	40V	20V	TO-92
	ZVP1304B	40V	20V	TO-39
	ZVP1306A	60V	20V	TO-92
	ZVP1306B	60V	20V	TO-39
International				
Rectifier	IRF9513	60V	20V	TO-220
Motorola	MTP8P08	80V	20V	TO-220
RCA	RFL1P08	80V	20V	TO-39
	RFT2P08	80V	20V	TO-220
Siliconix	VP0300B	30V	40V	TO-39
(preferred)	VP0300L	30V	40V	TO-92
	VP0300M	30V	40V	TO-237
	VP0808B	80V	40V	TO-39
	VP0808L	80V	40V	TO-92
	VP0808M	80V	40V	TO-237
Supertex	VP1304N2	40V	20V	TO-220
	VP1304N3	40V	20V	TO-92
	VP1306N2	60V	20V	TO-220
	VP1306N3	60V	20V	TO-92

NOTE: (1) $\mathrm{BV}_{\mathrm{DSS}}$ —Drain-source breakdown voltage. $\mathrm{BV}_{\mathrm{GS}}$ —Gate-source breakdown voltage.

TABLE I. Available P-Channel MOSFETs.

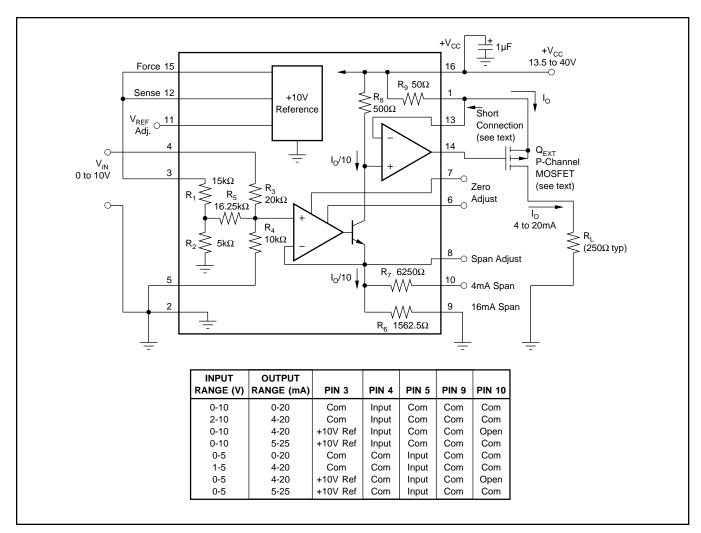


FIGURE 1. Basic Circuit Connection.



If the supply voltage, $+V_{CC}$, exceeds the gate-to-source breakdown voltage of Q_{EXT} , and the output connection (drain of Q_{EXT}) is broken, Q_{EXT} could fail. If the gate-to-source breakdown voltage is lower than $+V_{CC}$, Q_{EXT} can be protected with a 12V zener diode connected from gate to source.

Two PNP discrete transistors (Darlington-connected) can be used for Q_{EXT} —see Figure 2. Note that an additional capacitor is required for stability. Integrated Darlington transistors are not recommended because their internal base-emitter resistors cause excessive error.

TRANSISTOR DISSIPATION

Maximum power dissipation of Q_{EXT} depends on the power supply voltage and full-scale output current. Assuming that the load resistance is low, the power dissipated by Q_{EXT} is:

$$P_{MAX} = (+V_{CC}) I_{FS}$$
 (2)

The transistor type and heat sinking must be chosen according to the maximum power dissipation to prevent overheating. See Table II for general recommendations.

PACKAGE TYPE	ALLOWABLE POWER DISSIPATION
TO-92	Lowest: Use minimum supply and at +25°C.
TO-237	Acceptable: Trade-off supply and temperature.
TO-39	Good: Adequate for majority of designs.
TO-220	Excellent: For prolonged maximum stress.
TO-3	Use if hermetic package is required.

TABLE II. External Transistor Package Type and Dissipation.

INPUT VOLTAGE RANGE

The internal op amp A_1 can be damaged if its non-inverting input (an internal node) is pulled more than 0.5V below common (0V). This could occur if input pins 3, 4 or 5 were driven with an op amp whose output could swing negative under abnormal conditions. The voltage at the input of A_1 is:

$$V_{A1} = \frac{(V_{REF IN})}{16} + \frac{(V_{IN1})}{4} + \frac{(V_{IN2})}{2}$$
 (3)

This voltage should not be allowed to go more negative than -0.5V. If necessary, a clamp diode can be connected from the negative-going input to common to clamp the input voltage.

COMMON (Ground)

Careful attention should be directed toward proper connection of the common (grounds). All commons should be joined at one point as close to pin 2 of the XTR110 as possible. The exception is the I_{OUT} return. It can be returned to any point where it will not modulate the common at pin 2.

VOLTAGE REFERENCE

The reference voltage is accurately regulated at pin 12 $(V_{REF,SENSE})$. To preserve accuracy, any load including pin

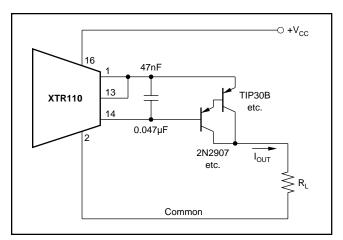


FIGURE 2. Q_{EXT} Using PNP Transistors.

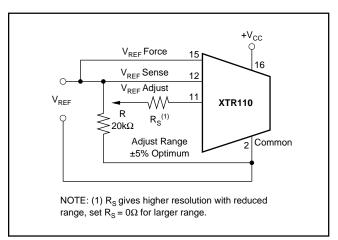


FIGURE 3. Optional Adjustment of Reference Voltage.

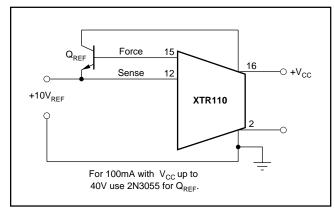


FIGURE 4. Increasing Reference Current Drive.

3 should be connected to this point. The circuit in Figure 3 shows adjustment of the voltage reference.

The current drive capability of the XTR110's internal reference is 10mA. This can be extended if desired by adding an external NPN transistor shown in Figure 4.

OFFSET (ZERO) ADJUSTMENT

The offset current can be adjusted by using the potentiometer, R_1 , shown in Figure 5. Set the input voltage to zero and then adjust R_1 to give 4mA at the output. For spans starting

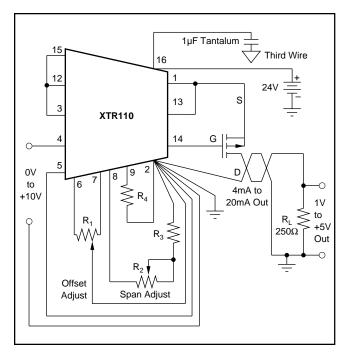


FIGURE 5. Offset and Span Adjustment Circuit for 0V to +10V Input, 4mA to 20mA Output.

at 0mA, the following special procedure is recommended: set the input to a small nonzero value and then adjust R_1 to the proper output current. When the input is zero the output will be zero. Figures 6 and 7 show graphically how offset is adjusted.

SPAN ADJUSTMENT

The span is adjusted at the full-scale output current using the potentiometer, R_2 , shown in Figure 5. This adjustment is interactive with the offset adjustment, and a few iterations may be necessary. For the circuit shown, set the input voltage to +10V full scale and adjust R_2 to give 20mA full-scale output. Figures 6 and 7 show graphically how span is adjusted.

The values of R_2 , R_3 , and R_4 for adjusting the span are determined as follows: choose R_4 in series to slightly decrease the span; then choose R_2 and R_3 to increase the span to be adjustable about the center value.

LOW TEMPERATURE COEFFICIENT OPERATION

Although the precision resistors in the XTR110 track within 1ppm/°C, the output current depends upon the absolute temperature coefficient (TC) of any one of the resistors, R_6 , R_7 , R_8 , and R_9 . Since the absolute TC of the output current can have 20ppm/°C, maximum, the TC of the output current can have 20ppm/°C drift. For low TC operation, zero TC resistors can be substituted for either the span resistors (R_6 or R_7) or for the source resistor (R_9) but not both.

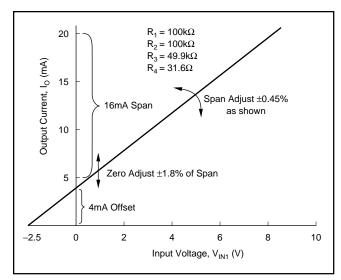


FIGURE 6. Zero and Span of 0V to +10V Input, 4mA to 20mA Output Configuration (see Figure 5).

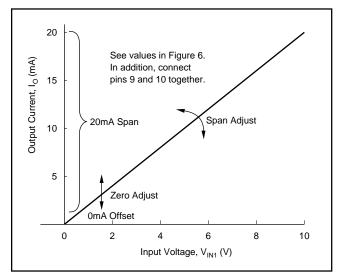


FIGURE 7. Zero and Span of 0V to $+10V_{IN}$, 0mA to 20mA Output Configuration (see Figure 5).

EXTENDED SPAN

For spans beyond 40mA, the internal 50Ω resistor (R₉) may be replaced by an external resistor connected between pins 13 and 16.

Its value can be calculated as follows:

$$R_{EXT} = R_9 (Span_{OLD}/Span_{NEW})$$

Since the internal thin-film resistors have a 20% absolute value tolerance, measure R_9 before determining the final value of $R_{\rm EXT}$. Self-heating of $R_{\rm EXT}$ can cause nonlinearity. Therefore, choose one with a low TC and adequate power rating. See Figure 10 for application.



TYPICAL APPLICATIONS

The XTR110 is ideal for a variety of applications requiring high noise immunity current-mode signal transmission. The precision +10V reference can be used to excite bridges and transducers. Selectable ranges make it very useful as a precision programmable current source. The compact design

and low price of the XTR110 allow versatility with a minimum of external components and design engineering expense.

Figures 8 through 10 show typical applications of the XTR110.

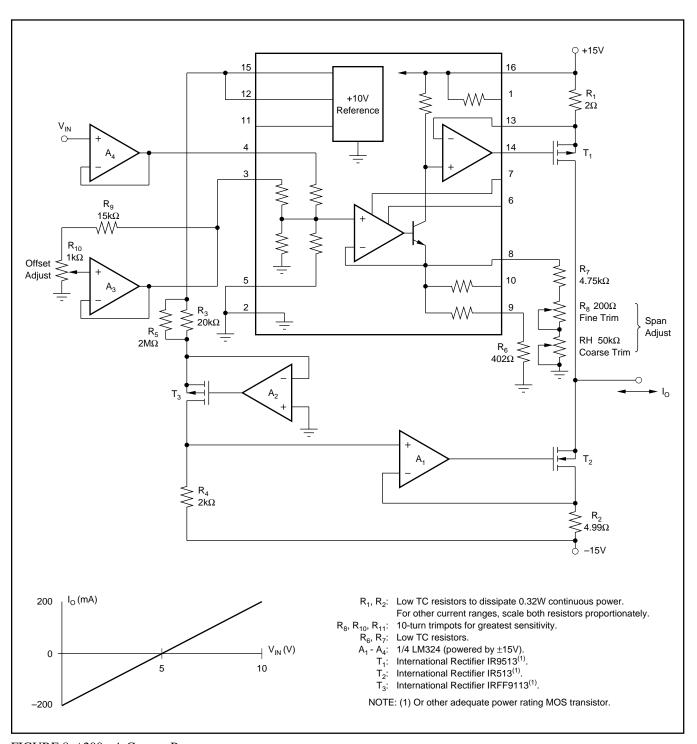


FIGURE 8. ±200mA Current Pump.

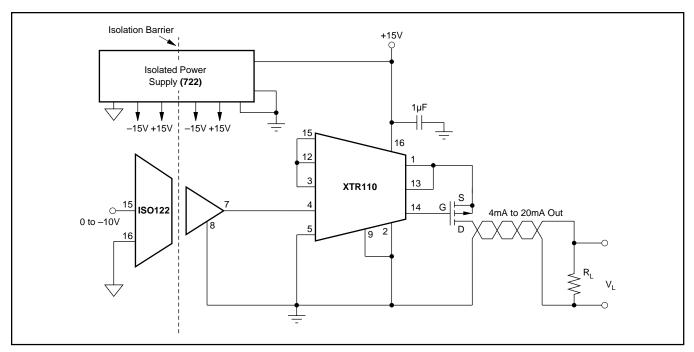


FIGURE 9. Isolated 4mA to 20mA Channel.

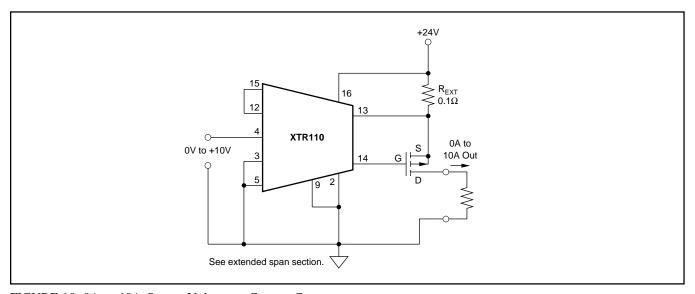


FIGURE 10. 0A to 10A Output Voltage-to-Current Converter.

Revision History

DATE	REVISION	PAGE	SECTION	DESCRIPTION
9/09			Front Page	Changed front page to standard format.
3,09		3	Applications Information	Changed text in third paragraph.

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.









17-Mar-2017

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
XTR110AG	NRND	CDIP SB	JD	16	1	Green (RoHS & no Sb/Br)	AU	N / A for Pkg Type		XTR110AG	
XTR110BG	NRND	CDIP SB	JD	16	1	Green (RoHS & no Sb/Br)	AU	N / A for Pkg Type		XTR110BG	
XTR110KP	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type		XTR110KP	Samples
XTR110KPG4	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type		XTR110KP	Samples
XTR110KU	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR		XTR110KU	Samples
XTR110KU/1K	ACTIVE	SOIC	DW	16	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR		XTR110KU	Samples
XTR110KU/1KG4	ACTIVE	SOIC	DW	16	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR		XTR110KU	Samples
XTR110KUG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR		XTR110KU	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

17-Mar-2017

- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

14-Jul-2012 www.ti.com

TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
XTR110KU/1K	SOIC	DW	16	1000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 14-Jul-2012



*All dimensions are nominal

Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
XTR110KU/1K	SOIC	DW	16	1000	367.0	367.0	38.0	

DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AA.



DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

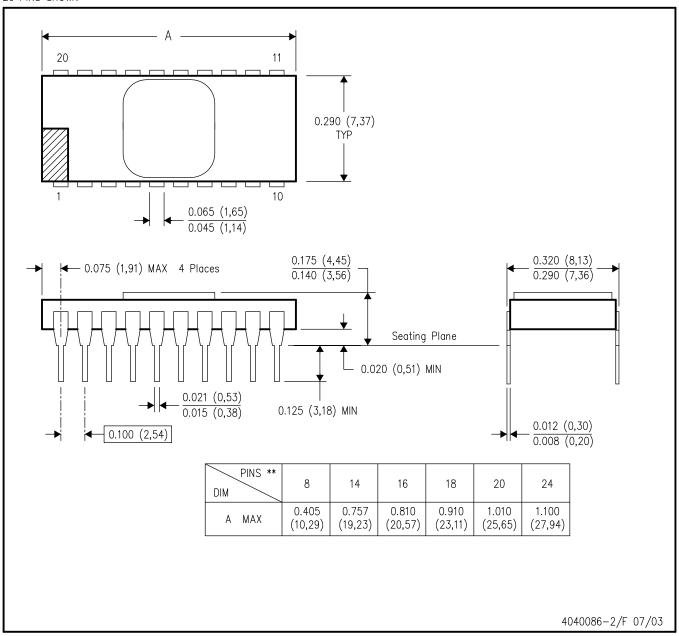
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



JD (R-CDIP-T**)

CERAMIC SIDE-BRAZE DUAL-IN-LINE PACKAGE

20 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a metal lid.
- D. The terminals are gold plated.
- E. Falls within MIL STD 1835 CDIP2 T8, T14, T16, T18, T20 and T24 respectively.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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